

# **Isc N-Channel MOSFET Transistor**

# STW45NM60

## • FEATURES

- High dv/dt and avalanche capabilities
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Tight process control and high manufacturing yields
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

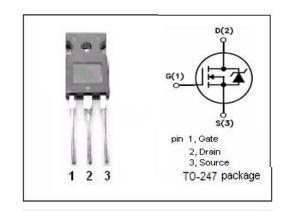
Switching application

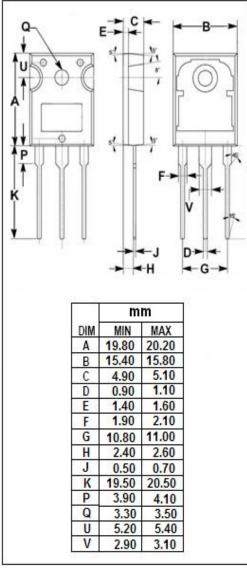


SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	600	V	
V <sub>GSS</sub>	Gate-Source Voltage	±30	V	
I <sub>D</sub>	Drain Current-Continuous@ $T_c$ =25° $C$ $T_c$ =100° $C$	45 28	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	180	А	
P <sub>D</sub>	Total Dissipation	417	W	
T <sub>ch</sub>	Max. Operating Junction Temperature	150	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature	-65~150	${\mathbb C}$	

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.3	°C/W	
Rth(ch-a)	a) Channel-to-ambient thermal resistance		°C/W	







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = ±30V; I <sub>D</sub> =0.25mA	3		5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =22.5A		90	110	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V; T <sub>J</sub> =25°C T <sub>J</sub> =125°C			10 100	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =45A, V <sub>GS</sub> = 0 V			1.5	V

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